

# Radiation 101: Effects on Hardware and Robotic Systems

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## Space environments



- Particle radiation High-energy electrons, protons & heavy ions
  - Solar particles (electrons, protons, and heavy ions),
  - Galactic cosmic rays (GCRs), and
  - Particles trapped in planetary magnetospheres.

#### Plasma

- lonosphere
- Plasmasphere magnetosphere
- Solar wind
- Neutral gas particles
  - Lower atomic oxygen (AO)
  - Higher hydrogen & helium
- Ultraviolet and X-ray photons
- Micrometeoroids & orbital debris

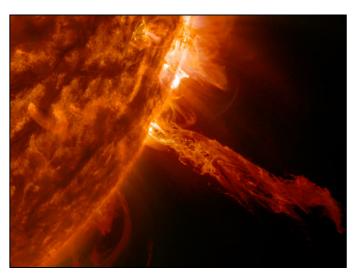


Image credit: Solar Dynamics Observatory/NASA http://sdo.gsfc.nasa.gov/gallery/main/item/520

## Space radiation environment



#### Space Weather

 "conditions on the sun and in the solar wind, magnetosphere, ionosphere, and thermosphere that can influence the performance and reliability of space-borne and ground-based technological systems and can endanger human life or health"

#### [US National Space Weather Program]

### Space> Climate

 "The historical record and description of average daily and seasonal <space> weather events that help describe a region. Statistics are usually drawn over several decades."

[Dave Schwartz the Weatherman – Weather.com]

M. A. Xapsos, et al., "Space Weather Effects on Spacecraft," Spacecraft Anomalies and Failures Workshop, Chantilly, VA, 2013.

## Objectives



- Increase knowledge of radiation effects amongst
  - Space weather professionals,
  - Space operations community, and
  - Other science and engineering stakeholders.
- Provide overview of
  - Total ionizing dose (TID),
  - Displacement damage (DD) / non-ionizing energy loss (NIEL), and
  - Single-event effects (SEE).

Stop me any time to ask questions

## A little radiation effects history...

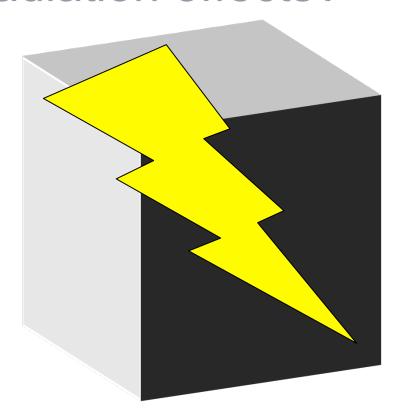


- Radiation effects community started during the Cold War
- Sputnik, 4 Oct 1957
- Van Allen Belts, Jan & Mar 1958 (Explorer I and III)
- Space Race started; Space Act signed into law by President Eisenhower on 29 Jul 1958
- President Kennedy was in office
  - o "Going to the Moon Speech," 25 May 1961 / 12 Sep 1962
    - » US Congress / Rice Stadium, TX
- STARFISH PRIME (Ops. Fishbowl / Dominic) 9 Jul 1962
- Limited Test Ban Treaty, 5 Aug 1963

E. E. Conrad, "Reflections on 47+ Years of NSREC," presented at the *IEEE Nuclear and Space Radiation Effects Conf.*, Denver, CO, Jul. 2010.

## What are radiation effects?





- Energy deposition rate in a "box"
- Source of energy and how it's absorbed control the observed effects

# What makes radiation effects so challenging?



- Field is still evolving because of the technologies we want to use in space systems
- A problem of dynamic range
  - Length:  $10^{16} \text{ m} \rightarrow 10^{-15} \text{ m}$  (1 light year, 1 fm) »  $10^{31}$
  - Energy: 10<sup>19</sup> eV → 1 eV (extreme energy cosmic rays, silicon band gap)
    - » 10<sup>19</sup>
  - Those are just two dimensions there are many others
    - » Radiation sources, electronic technologies, etc.
- Variability and ultimate knowledge of the environment

## What is a rad?



- 1 rad = 100 erg/g = 0.01 J/kg; 100 rad = 1 Gy
  - Always specified for a particular material
  - 1 rad(SiO<sub>2</sub>), 10 krad(Si), 100 Gy(H<sub>2</sub>O)
- This is absorbed dose, not exposure (R), or dose equivalent (Sv)
- Missions have a wide range of absorbed dose requirements, driven in large part by persistent environment components
  - Trapped particles, solar protons, etc.

# What is total ionizing dose (TID)?



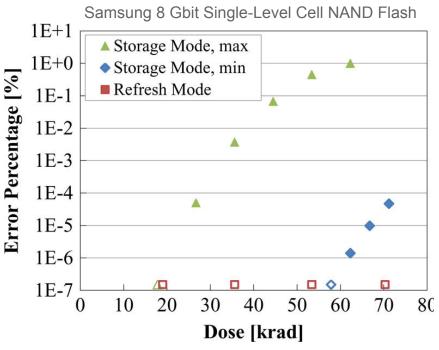
- TID is the absorbed dose in a given material resulting from the energy deposition of ionizing radiation.
- TID results in cumulative parametric degradation that can lead to functional failure. This is analogous to wear out.
- In space, caused mainly by protons and electrons.

#### Examples

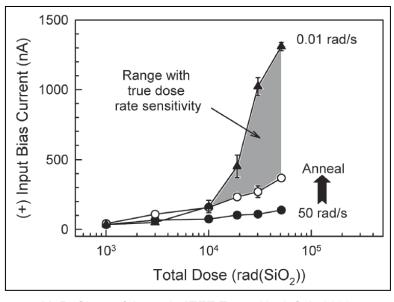
Metal Oxide Semiconductors Devices	Bipolar Devices
Threshold voltage shifts	Excess base current
Increased off-state leakage	Changes to recombination behavior

## TID effects





I<sub>B+</sub> vs. Total Dose for LM111 Voltage Comparators



M. R. Shaneyfelt, et al., IEEE Trans. Nucl. Sci., 2000.

- H. Schmidt, et al., IEEE Trans. Nucl. Sci., 2009.
- Caused by the energy deposition of protons, electrons, energetic heavy ions, and photon-material interactions – <u>tends to be focused on</u> <u>insulators</u>
- Holes (as opposed to electrons) build up in deep traps and interface traps, which are manifest as electrical changes in device performance

## What is non-ionizing energy loss (NIEL)?

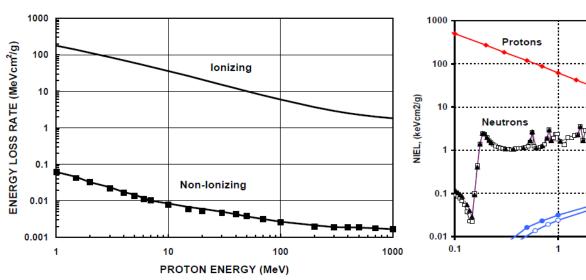


- Most always a result of protons and electrons.
- Vast majority of incident kinetic energy lost to direct ionization, creating TID and other radiation effects.
- A small portion of energy lost in non-ionizing processes causes atoms to be removed from their lattice sites and form permanent electrically-active defects (*i.e.*, displacement damage) in semiconductor materials.
- Non-ionizing energy loss (NIEL) is that part of the energy introduced via both Coulomb (elastic), nuclear elastic, and nuclear inelastic interactions, which produces the initial vacancy-interstitial pairs and phonons (e.g., vibrational energy).

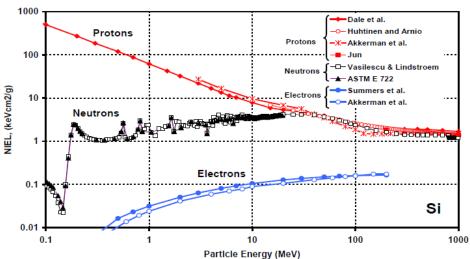
## What is NIEL?



#### Silicon Material System



C. J. Marshall, IEEE NSREC Short Course, 2009.



C. Poivey & G. Hopkinson, "Displacement Damage Mechanism and Effects," Space Radiation and its Effect on EEE Components, EPFL Training Course, 2009.

 Non-ionizing energy causes cumulative damage, much like TID

NSREC: Nuclear and Space Radiation Effects Conference

## What is displacement damage?



- Displacement damage dose is the non-ionizing energy loss (NIEL) in a given material resulting from a portion of energy deposition by impinging radiation.
- Displacement damage is cumulative parametric degradation that can lead to functional failure.
  This is analogous to wear out.
- In space, caused mainly by protons and electrons.

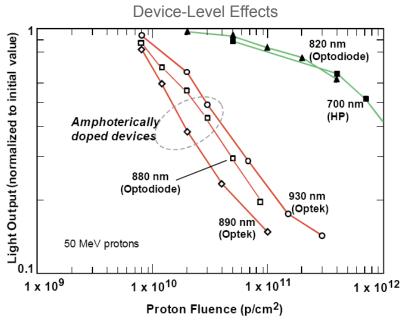
#### **Displacement Damage Dose Effects**

Degraded minority carrier lifetime (e.g., gain reductions, effects in LEDs and optical sensors, etc.)

Changes to mobility and carrier concentrations

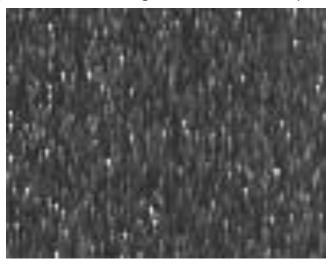
## Displacement damage effects





A. Johnston, IEEE NSREC Short Course, 2000.

Dark Spikes and CTI damage - 1.8x10<sup>10</sup> 10 MeV protons/cm<sup>2</sup>



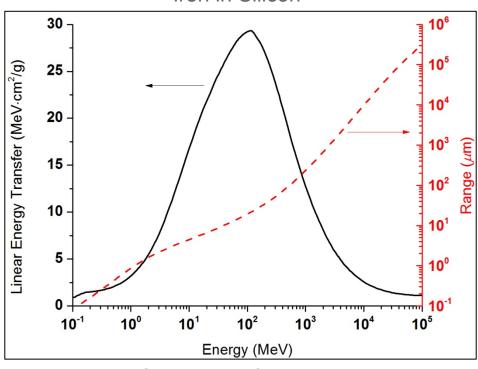
C. Poivey & G. Hopkinson, "Displacement Damage Mechanism and Effects," Space Radiation and its Effect on EEE Components, EPFL Training Course, 2009.

- Displacement damage tends to affect bipolar, optical, and optoelectronic systems the most – not always true. (Material effects are a separate topic)
- Which defects are electrically active? Synergy with TID & singleevent effects...

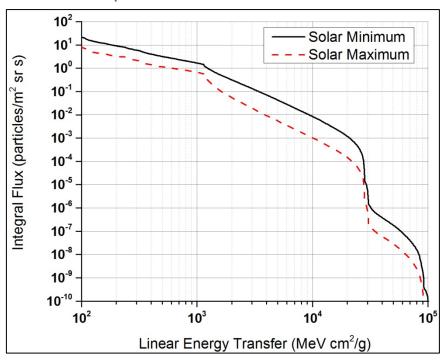
# What is linear energy transfer (LET)?



#### Iron in Silicon



GEO LET Spectrum behind 2.5 mm of Aluminum



Generated with SRIM-2008

Generated with CREME96

$$S = -\frac{dE}{dx} \Rightarrow \text{LET} = -\frac{1}{\rho} \frac{dE}{dx}$$

Stopping power (S), depends on target material; LET does not

# What are single-event effects (SEE)?



- A SEE is a disturbance to the normal operation of a circuit caused by the passage of a single ion (proton or heavy ion) through or near a sensitive node in a circuit.
- SEEs can be either destructive or non-destructive.

#### Examples

Non-Destructive	Destructive	
Single-Event Upset (SEU)	Single-Event Latchup (SEL)	
Multiple-Bit Upset (MBU) Single-Event Burnout (SEB)		
Single-Event Transient (SET)	Single-Event Gate Rupture (SEGR)	
Single-Event Functional Interrupt (SEFI)		

After S. Buchner, SERESSA 2011 Course, Toulouse, France.

## Proton SEE notes



- Proton LET is very low (<< 1 MeV-cm<sup>2</sup>/mg)
  - Upsets are usually dominated by indirect ionization nuclear reactions
  - Reaction products have appreciable LETs, usually less than 15 MeV-cm<sup>2</sup>/mg, but short ranges compared to GCRs
  - Since 2007, direct ionization SEE from low-energy protons have become relevant (increasing device sensitivity)
- Importance of proton SEE
  - In proton-dominated environments, can be a large portion of the overall SEE rate – LEO, for instance

## Short history of SEE

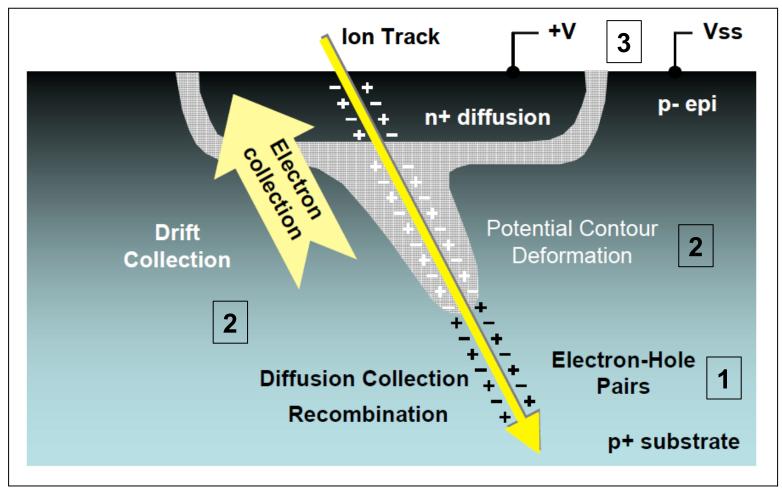


- The possibility of single event upsets was first postulated in 1962 by Wallmark and Marcus. J.T. Wallmark, S.M. Marcus, "Minimum size and maximum packaging density of non-redundant semiconductor devices," Proc. IRE, vol. 50, pp. 286-298, March 1962.
- The first actual satellite anomalies were reported in 1975. SEUs in flip-flops. D. Binder, E.C. Smith, A.B. Holman, "Satellite anomalies from galactic cosmic rays," IEEE Trans. on Nuclear Science, vol. 22, no. 6, pp. 2675-2680, Dec. 1975.
- First observation of SEUs on earth was in 1978. Observed in RAM caused by the alpha particles released by U and Th contaminants within the chip packaging material and solder. Vendors took specific actions to reduce it. T. C. May and M. H. Woods, "A New Physical Mechanism for Soft Errors in Dynamic Memories", Proceedings 16 Int'l Reliability Physics Symposium, p. 33, April, 1978.
- First report of SEUs due to cosmic rays on earth in 1979. J. F. Ziegler and W. A. Lanford, "Effect of Cosmic Rays on Computer Memories", Science, 206, 776 (1979).
- First report of destructive SEE (proton induced latch-up) in a memory operating in space in 1992 L. Adams et al., "A Verified Proton Induced Latch-up in Space," IEEE TNS vol. 39, No. 6, pp. 1804 1808, Dec. 1992.

After S. Buchner, SERESSA 2011 Course, Toulouse, France.

# SEE processes - briefly

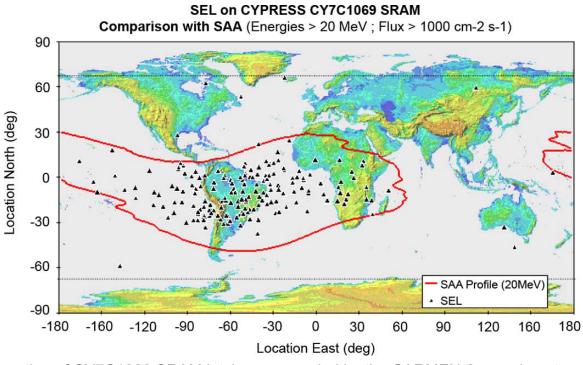




R. Baumann, IEEE NSREC Short Course, 2005.

## SEE - latchup





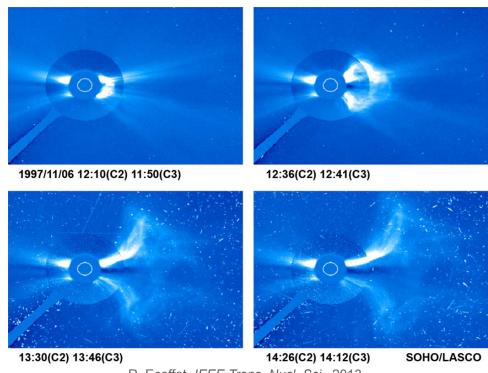
Location of CY7C1069 SRAM latch-ups recorded by the CARMEN-2 experiment on JASON-2 R. Ecoffet, *IEEE NSREC Short Course*, 2011.

 Events are likely due to proton indirect ionization and/or cosmic rays

## SEE – sensor corruption



Solar Particle Event Tracks on SOHO LASCO Instrument



R. Ecoffet, IEEE Trans. Nucl. Sci., 2013.

 Transient imager corruption due to solar particle event protons and ions striking the device

The SOHO/LASCO data used here are produced by a consortium of the Naval Research Laboratory (USA), Max-Planck-Institut fuer Aeronomie (Germany), Laboratoire d'Astronomie (France), and the University of Birmingham (UK). SOHO is a project of international cooperation between ESA and NASA.

## Summary



- Hardware radiation effects rely on both space climate and space weather for design and operational effectiveness
- Radiation effects electronic, optical, and optoelectronic, and material systems deployed into the space environment
- Performance impacts can be manifest as cumulative degradation (e.g., TID and DD) or transient effects (e.g., SEE, may be destructive)

# Acronyms



Acronym	Definition
AIEE	American Institute of Electrical Engineers
CTI	Charge Transfer Inefficiency
DDD	Displacement Damage Dose
ELDRS	Enhanced Low Dose Rate Sensitivity
GCR	Galactic Cosmic Ray
GEO	Geostationary Orbit
IRE	Institute of Radio Engineers
LASCO	Large Angle and Spectrometric Coronagraph Experiment
LEO	Low Earth Orbit
LET	Linear Energy Transfer
MBU	Multiple Bit Upset
MEAL	Mission, Environment, Application, and Lifetime
NEPP	NASA Electronic Parts and Packaging program
NESC	NASA Engineering & Safety Center
NIEL	Non-Ionizing Energy Loss
NSREC	Nuclear and Space Radiation Effects Conference
RAM	Random Access Memory
SAA	South Atlantic Anomaly
SEB	Single-Event Burnout
SEE	Single-Event Effects
SEFI	Single-Event Functional Interrupt
SEGR	Single-Event Gate Rupture
SEL	Single-Event Latchup
SET	Single-Event Transient
SEU	Single-Event Upset
SOHO	Solar & Heliospheric Observatory
SRAM	Static Random Access Memory
TID	Total Ionizing Dose